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SEMICONDUCTOR

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FSTU16245 16-Bit Bus Switch with –2V Undershoot Protection

General Description

The Fairchild Switch FSTU16245 provides 16-bits of highspeed CMOS TTL-compatible bus switching. The low On Resistance of the switch allows inputs to be connected to outputs without adding propagation delay or generating additional ground bounce noise.

The device is organized as a 16-bit switch. There are two 8-bit switches with separate output enable inputs. When OE is LOW, the switch is ON and Port a is connected to Port B. When OE is HIGH, the switch is OFF and a high impedance state exists between the A and B Ports. The A and B Ports are protected against undershoot to support an extended range to 2.0V below ground. Fairchild's integrated Undershoot Hardened Circuit (UHC™) senses undershoot at the I/O and responds by preventing voltage differentials from developing and turning the switch on. When OE is HIGH, the switch is OPEN and a high-impedance state exists between the two ports.

Features

- Undershoot hardened to -2V (A and B Ports)
- **4**Ω switch connection between two ports.
- Minimal propagation delay through the switch.
- Low I_{CC}.
- Zero bounce in flow-through mode.
- Control inputs compatible with TTL level.
- See Application Note AN-5008 for details



Ordering Code:

Order Number	Package Number	Package Description	-		
FSTU16245MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide			
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.					

Connection Diagram

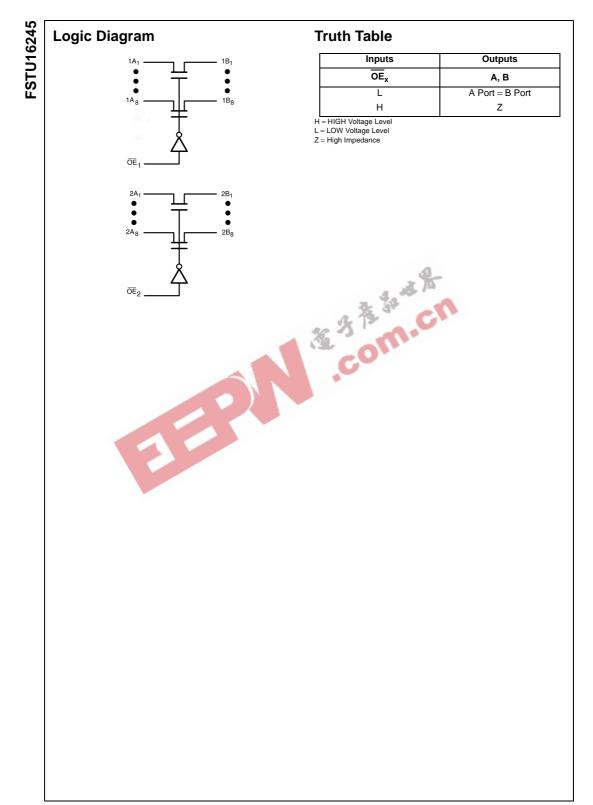
	ayran		
		_	1
NC -	1	48	- OE1
18 ₁ _	2	47	— 1A ₁
18 ₂ _	3	46	-1A ₂
GND -	4	45	- GND
1B3 —	5	44	-1A3
1B ₄	6	43	- 1A4
V _{CC}	7	42	-v _{cc}
^{1B} 5 —	8	41	- 1A5
18 ₆ —	9	40	- 1A ₆
GND —	10	39	- GND
1B ₇ _	11	38	— 1A ₇
18 ₈	12	37	— 1 A ₈
28 ₁ _	13	36	— 2A1
²⁸ 2 —	14	35	-2A2
GND 🗕	15	34	- GND
^{2B} 3	16	33	- 2A3
28 ₄ _	17	32	-2A4
V _{cc} _	18	31	- v _{cc}
28 ₅	19	30	- 2A5
²⁸ 6 —	20	29	- 2A ₆
GND —	21	28	- GND
28 ₇	22	27	- 2 A ₇
28 ₈ -	23	26	- 2A8
NC —	24	25	- 0E2
			l

Pin Descriptions

Pin Name	Description			
OEn	Output Enable Input (Active LOW)			
1A _n , 2A _n , 3A _n , 4A _n	Bus A			
1B _n , 2B _n , 3B _n , 4B _n	Bus B			
NC	No Internal Connection			

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Absolute Maximum Ratings(Note 1)

Supply Voltage (V _{CC})	-0.5V to +7.0V
DC Switch Voltage (V _S) (Note 2)	-2.0V to +7.0V
DC Input Voltage (V _{IN}) (Note 3)	-0.5V to +7.0V
DC Input Diode Current (I _{IK}) V _{IN} <0V	–50mA
DC Output Current (I _{OUT})	128mA
DC V _{CC} /GND Current (I _{CC} /I _{GND})	±100mA
Storage Temperature Range (T _{STG})	–65°C to +150 °C

Recommended Operating Conditions (Note 4)

Power Supply Operating (V _{CC)}	4.0V to 5.5V
Input Voltage (V _{IN})	0V to 5.5V
Output Voltage (V _{OUT})	0V to 5.5V
Input Rise and Fall Time (t _r , t _f)	
Switch Control Input	0nS/V to 5nS/V
Switch I/O	0nS/V to DC
Free Air Operating Temperature (T _A)	-40 °C to +85 °C

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum rating. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: V_S is the voltage observed/applied at either the A or B Ports across the switch.

Note 3: The input and output negative voltage ratings may be exceeded if

Note 3: The input and output hegative voltage raings may be exceeded if the input and output diode current ratings are observed. Note 4: Unused control inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V _{CC} (V)	Min	Typ (Note 5)	Max	Units	Conditions
V _{IK}	Clamp Diode Voltage	4.5			-1.2	V	$I_{IN} = -18 mA$
V _{IH}	HIGH Level Input Voltage	4.0-5.5	2.0			V	
V _{IL}	LOW Level Input Voltage	4.0-5.5			0.8	V	
l _l	Input Leakage Current	5.5			±1.0	μΑ	$0 \le V_{IN} \le 5.5V$
		0			10	μΑ	V _{IN} = 5.5V
I _{OZ}	OFF-STATE Leakage Current	5.5			±1.0	μΑ	$0 \le A, B \le V_{CC}$
R _{ON}	Switch On Resistance	4.5		4	7	Ω	$V_{IN} = 0V, I_{IN} = 64 \text{ mA}$
	(Note 6)	4.5		4	7	Ω	$V_{IN} = 0V, I_{IN} = 30 \text{ mA}$
		4.5		8	14	Ω	$V_{IN} = 2.4V, I_{IN} = 15 \text{ mA}$
		4.0		11	20	Ω	$V_{IN} = 2.4V, I_{IN} = 15 \text{ mA}$
I _{CC}	Quiescent Supply Current	5.5			3	μΑ	$V_{IN} = V_{CC}$ or GND, $I_{OUT} = 0$
ΔI_{CC}	Increase in I _{CC} per Input	5.5			2.5	mA	One input at 3.4V
							Other inputs at V _{CC} or GND
V _{IKU}	Voltage Undershoot	5.5			-2.0	V	$0.0 \text{ mA} \ge I_{IN} \ge -50 \text{ mA}$
							<u>OE</u> = 5.5V

Note 5: Typical values are at V_{CC} = 5.0V and T_A = +25 $^\circ C$

Note 6: Measured by the voltage drop between A and B pins at the indicated current through the switch. On Resistance is determined by the lower of the voltages on the two (A or B) pins.

FSTU16245 **AC Electrical Characteristics** $T_A = -40 \ ^\circ C$ to $+85 \ ^\circ C$, $C_L = 50 pF, RU = RD = 500 \Omega$ Figure Symbol Parameter Units Conditions $V_{CC} = 4.5 - 5.5V$ $V_{\text{CC}} = 4.0 \text{V}$ Number Min Max Min Max $V_I = OPEN$ 0.25 0.25 Prop Delay Bus-to-Bus (Note 7) Figures 2, 3 t_{PHL},t_{PLH} ns Output Enable Time Figures 2, 3 $t_{\mathsf{PZH}},\,t_{\mathsf{PZL}}$ 1.0 6.5 6.9 ns $V_I = 7V$ for t_{PZL} $V_I = OPEN$ for t_{PZH} Figures 2, 3 Output Disable Time 1.0 6.1 6.5 ns $V_{I}=7V$ for t_{PLZ} t_{PHZ}, t_{PLZ} $V_I = OPEN$ for t_{PHZ} Note 7: This parameter is guaranteed by design but is not tested. The bus switch contributes no propagation delay other than the RC delay of the typical On Resistance of the switch and the 50pF load capacitance, when driven by an ideal voltage source (zero output impedance). Capacitance (Note 8) Symbol Parameter Тур Max Units Conditions $V_{CC} = 5.0V, V_{IN} = 0V$ Control Pin Input Capacitance 3 C_{IN} рF Input/Output Capacitance "OFF State" V_{CC} , $\overline{OE} = 5.0V$, $V_{IN} = 0V$ C_{I/O} 6 pF Note 8: $T_A = +25^{\circ}C$, f = 1 MHz, Capacitance is characterized but not tested. 24 Undershoot Characteristic (Note 9) Symbol Parameter Min Conditions Тур Units Output Voltage During Undershoot VOUTU 2.5 V_{OH} - 0.3 V Figure 1 Note 9: This test is intended to characterize the device's protective capabi by maintaining output signal integrity during an input transient voltage undershoot event. V_{TR1} V_CC (V_{OUTU}) D.U.T. 1 OnF FIGURE 1. **Device Test Conditions** Transient Input Voltage (V_{IN}) Waveform Parameter Value Units V_{IN} see Waveform V 5.5V 100K $R_1 = R_2$ Ω V_{TRI} 11.0 V 5.5 ٧ V_{CC} 0V -2V

